

MECHANICAL and **PACKAGING**

- CASE: Industry standard TO-204AA (TO-3), hermetically sealed, 0.040 inch diameter pins
- FINISH: Solder dipped tin-lead over nickel plated alloy 52 or RoHS compliant matte-tin plating. Solderable per MIL-STD-750 method 2026.
- POLARITY: NPN (see <u>schematic</u>)
- MOUNTING HARDWARE: Consult factory for optional insulator and sheet metal screws
- WEIGHT: Approximately 15 grams
- See package dimensions on last page.

PART NOMENCLATURE **JAN** 2N6283 (e3)**RoHS Compliance Reliability Level** $\overline{JAN} = \overline{JAN}$ Level e3 = RoHS Compliant (available JANTX = JANTX Level on commercial grade only) Blank = non-RoHS Compliant JANTXV = JANTXV Level Blank = Commercial JEDEC type number (see Electrical Characteristics table)

SYMBOLS & DEFINITIONS					
Symbol	Definition				
I _B	Base current: The value of the dc current into the base terminal.				
Ic	Collector current: The value of the dc current into the collector terminal.				
Ι _Ε	Emitter current: The value of the dc current into the emitter terminal.				
T _C	Case temperature: The temperature measured at a specified location on the case of a device.				
V _{CB}	Collector-base voltage: The dc voltage between the collector and the base.				
V _{CBO}	Collector-base voltage, base open: The voltage between the collector and base terminals when the emitter terminal is open-circuited.				
V _{cc}	Collector-supply voltage: The supply voltage applied to a circuit connected to the collector.				
V _{CE}	Collector-emitter voltage: The dc voltage between the collector and the emitter.				
V _{CEO}	Collector-emitter voltage, base open: The voltage between the collector and the emitter terminals when the base terminal is open-circuited.				
V _{EB}	Emitter-base voltage: The dc voltage between the emitter and the base				
V _{EBO}	Emitter-base voltage, collector open: The voltage between the emitter and base terminals with the collector terminal open-circuited.				



ELECTRICAL CHARACTERISTICS @ T_A = +25 °C unless otherwise noted

Characteristics		Symbol	Min.	Max.	Unit
OFF CHARACTERISTICS					
Collector-Emitter Breakdown Voltage I _C = 100 mA	2N6283 2N6284	V _{(BR)CEO}	80 100		V
Collector-Emitter Cutoff Current V _{CE} = 40 V V _{CE} = 50 V	2N6283 2N6284	I _{CEO}		1.0 1.0	mA
Collector-Emitter Cutoff Current $V_{CE} = 80 \text{ V}, V_{BE} = 1.5 \text{ V}$ $V_{CE} = 100 \text{ V}, V_{BE} = 1.5 \text{ V}$	2N6283 2N6284	I _{CEX}		0.01 0.01	mA
Emitter-Base Cutoff Current V _{EB} = 7.0 V		I _{EBO}		2.5	mA

ON CHARACTERISTICS

Forward-Current Transfer Ratio $I_C = 1.0 \text{ A}, V_{CE} = 3.0 \text{ V}$ $I_C = 10 \text{ A}, V_{CE} = 3.0 \text{ V}$ $I_C = 20 \text{ A}, V_{CE} = 3.0 \text{ V}$	h _{FE}	1,500 1,250 500	18,000	
Collector-Emitter Saturation Voltage $I_C = 20 \text{ A}, I_B = 200 \text{ mA}$ $I_C = 10 \text{ A}, I_B = 40 \text{ mA}$	V _{CE(sat)}		3.0 2.0	\
Base-Emitter Saturation Voltage I _C = 20 A, I _B = 200 mA	V _{BE(sat)}		4.0	V
Base-Emitter Voltage Non-saturated V _{CE} = 3.0 V, I _C = 10 A	V_{BE}		2.8	V

DYNAMIC CHARACTERISTICS

Common Emitter Small-Signal Short-Circuit				
Forward Current Transfer Ratio	h _{fe}	700		
$I_C = 10 \text{ A}, V_{CE} = 3.0 \text{ V}, f = 1 \text{ kHz}$	тте	700		
Magnitude of Common Emitter Small-Signal Short-Circuit				
Forward Current Transfer Ratio	 h _{fe}	0	90	
$I_C = 10 \text{ A}, V_{CE} = 3.0 \text{ V}, f = 1 \text{ MHz}$	Intel	8	80	
Output Capacitance	C		250	nΕ
$V_{CB} = 10 \text{ V}, I_{E} = 0, f = 100 \text{ kHz} \le f \le 1 \text{ MHz}$	C _{obo}		350	pF



ELECTRICAL CHARACTERISTICS @ T_C = 25 °C unless otherwise noted. (continued)

SWITCHING CHARACTERISTICS

Turn-On Time $V_{CC} = 30 \text{ V}, I_C = 10 \text{ A}; I_B = 40 \text{ mA}$	t _{on}	2.0	μS
Turn-Off Time $V_{CC} = 30 \text{ V}, I_C = 10 \text{ A}; I_{B1} = I_{B2} = 40 \text{ mA}$	t _{off}	10	μS

SAFE OPERATING AREA (See Figures 1 and 2 below and MIL-STD-750,Test Method 3053)

DC Tests

 T_C = +25 °C, +10 °C, -0 °C, t ≥ 1 second, 1 Cycle

Test 1

 $V_{CE} = 8.75 \text{ V}, I_{C} = 20 \text{ A}$

Test 2

 $V_{CE} = 30 \text{ V}, I_{C} = 5.8 \text{ A}$

Test 3

 $V_{CE} = 80 \text{ V}, I_{C} = 100 \text{ mA } (2N6283)$

 $V_{CE} = 100 \text{ V}, I_{C} = 100 \text{ mA} (2N6284)$



SAFE OPERATING AREA

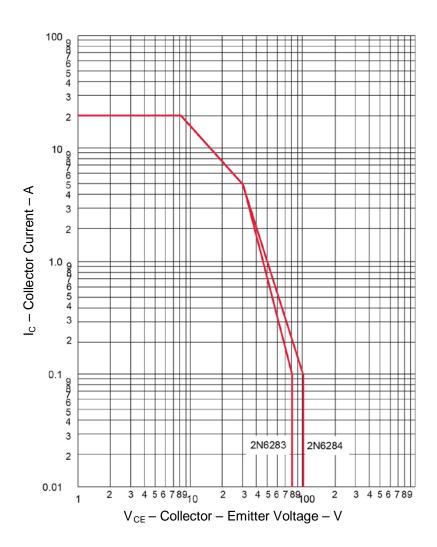


FIGURE 1

Maximum Safe Operating Area
(continuous dc)



SAFE OPERATING AREA (continued)

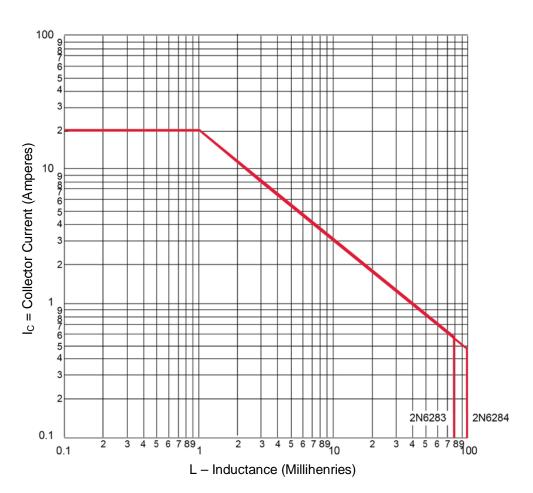


FIGURE 2
Safe Operating Area for Switching Between Saturation and Cutoff (unclamped inductive load)



GRAPHS

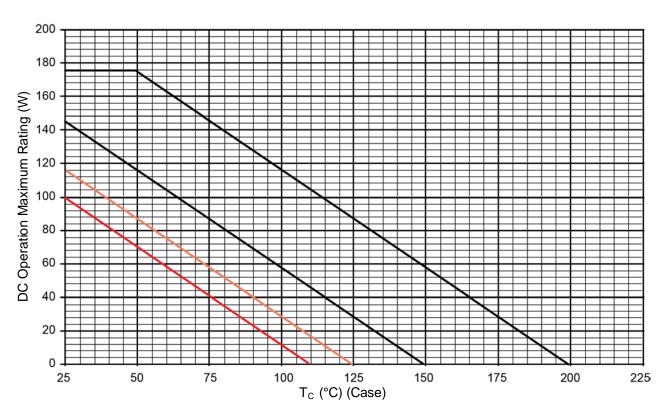
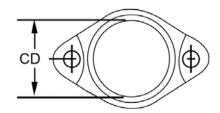
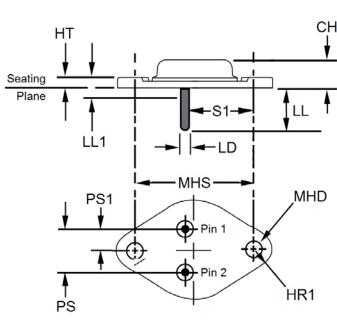


FIGURE 1
Temperature – Power Derating Curve



PACKAGE DIMENSIONS





Ltr	Inches		Millim	Notes	
	Min	Max	Min	Max	
CD	-	0.875	-	22.23	3
CH	0.250	0.328	6.35	8.33	
HR	0.495	0.525	12.57	13.34	
HR1	0.131	0.188	3.33	4.78	6
HT	0.060	0.135	1.52	3.43	
LD	0.038	0.043	0.97	1.09	4, 5, 9
LL	0.312	0.500	7.92	12.70	4, 5, 9
LL1	1	0.050	1	1.27	5, 9
MHD	0.151	0.161	3.84	4.09	7
MHS	1.177	1.197	29.90	30.40	
PS	0.420	0.440	10.67	11.18	
PS1	0.205	0.225	5.21	5.72	5
S1	0.655	0.675	16.64	17.15	

NOTES:

- 1. Dimensions are in inches. Millimeters are given for information only.
- 2. Millimeters are given for information only.
- 3. Body contour is optional within zone defined by CD.
- 4. These dimensions shall be measured at points .050 inch (1.27 mm) to .055 inch (1.40 mm) below seating plane. When gauge is not used, measurement shall be made at seating plane.
- 5. Both terminals.
- 6. At both ends.
- 7. Two holes.
- 8. The collector shall be electrically connected to the case.
- 9. LD applies between L1 and LL. Lead diameter shall not exceed twice LD within L1.
- 10. The seating plane of the header shall be flat within .001 inch (0.03 mm), concave to .004 inch (0.10 mm), convex inside a .930 inch (23.62 mm) diameter circle on the center of the header, and flat within .001 inch (0.03 mm) concave to .006 inch (0.15 mm), convex overall.
- 11. In accordance with ASME Y14.5M, diameters are equivalent to Φx symbology.



SCHEMATIC

